

## Claim Sheet – Preliminary Amendment

Docket 261/136

91. A method for cleaning a semiconductor article, comprising the steps of:  
contacting the article with an oxidizing solution;  
rinsing the article; and  
exposing the article to a vapor comprising ozone.
92. A method for cleaning a surface of a semiconductor article, comprising the steps of:  
loading the semiconductor article into a chamber;  
providing a heated liquid solution onto the surface of the article within the chamber, the solution including deionized water;  
providing ozone into the chamber; and  
rotating the article within the chamber with the heated liquid solution on the surface of the article.
93. The method of claim 92 where the solution is heated to a temperature between room temperature and 100°C.
94. The method of claim 92 where the solution is heated to a temperature between 50-90°C.
95. The method of claim 92 where the article is rotated at 200-2000rpm.
96. The method of claim 91 with the liquid further including hydrogen flouride.

97. A method for cleaning a semiconductor article, comprising the steps of:  
contacting the article with a heated oxidizing solution;  
exposing the article to a vapor comprising ozone;  
rotating the article; and  
rinsing the article.

Cont  
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1. The first part of the report, "The State of the Union", is a general statement of the condition of the country, and is followed by a detailed account of the progress of the war.